Multiscale simulations of the density of states, DC and THz mobility of charge carriers in disordered conjugated polymers



Nenad Vukmirović Scientific Computing Laboratory Institute of Physics Belgrade, Serbia

> email: nenad@ipb.ac.rs URL: www.scl.rs/nenad

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Introduction

- Mobility at high (THz) frequencies is more relevant than DC mobility in many cases (e.g. bulk heterojunctions)
- In this work
 - •Extension of previous atomistic multiscale methodology for simulation of DC transport in disordered polymers.
 - Identification of the origin of THz mobility
 - •How far are carriers probed by THz radiation traveling?
 - •What are they hopping times?
 - Identification of parameters that affect the THz mobility
 - Energetic disorder
 - •Temperature
 - Presence/absence of side chains
 - •Comparison with TR THz spectroscopy.







N. Vukmirović and L.-W. Wang, Nano Lett. 9, 3996 (2009)



Multiscale method for THz carrier transport



ABORATORY

Calculation of terahertz mobility

•Rate equations for populations of electronic states

$$\frac{\mathrm{d}n_i}{\mathrm{d}t} = \sum_j A_{ij} n_j$$
$$A_{ij} = W_{ji} - \delta_{ij} \sum_k W_{ik}$$

Kubo's linear response formula

$$\mu(\omega) = -\frac{e\omega^2}{2k_{\rm B}T} \int_0^\infty dt e^{i\omega t} \langle \Delta^2(t) \rangle$$
$$\mu(\omega) = -\frac{e\omega^2}{2k_{\rm B}T} \sum_{i,a} w_a \left(\mathbf{R}_i - \mathbf{R}_a \right)^2 \left[(i\omega - [A])^{-1} \right]_{ia}$$



Polymer materials in this study

Alternating polyfluorene (APFO-3)



- Material in polymer and monomer form with and without alkyl side chains.
- Stiff interring torsion barriers of 250 and 120 meV (vs. 80meV for P3HT)
- Experimental data on THz mobility available (University of Lund, Villy Sundstrom group).

Frequency dependence of mobility at 300K

• Hole mobility in APFO-3



• The shape of the spectrum suggests that above THz hopping rates are present in the system.



What does THz radiation actually probe?

Distance-resolved mobility:



High frequency (10 THz) – one or two hops are actually probed.
Low frequency (0.1 THz) – transport over ~10nm is probed.



Temperature dependence of THz mobility

Energy-resolved mobility

Temperature dependence



 Thermally activated transport, but with a much smaller activation energy (~115meV) compared to the DC case (~250meV).



Schematic comparison of DC and THz transport



Comparison of THz mobilities of similar materials

- APFO-3 polymer material with alkyl side chains
- APFO-3 monomer material without alkyl side chains
- APFO-3 monomer material with alkyl side chains



Energetic disorder as the origin of this behavior



Conclusion

 Identification of the origin of THz mobility How far are carriers probed by THz radiation traveling? •Answer: high f – 1 or 2 hops, low f – transport over ~10nm •What are they hopping times? Answer: above THz hopping rates are present Identification of parameters that affect the THz mobility Energetic disorder Answer: Reduces THz mobility •Temperature •Answer: Thermally activated transport but with significantly smaller activation energy than for DC transport Presence of side chains Answer: Reduces disorder and increases THz mobility

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